DESCRIPTION

The US2AF~US2MF are available in SMAF package

FEATURES

- For surface mounted applications
- Low profile package
- Glass Passivated Chip Junction
- Easy to pick and place
- High efficiency
- Available in SMAF package

ORDERING INFORMATION

Package Type	Part Number				
	US2AF				
SMAF	US2BF				
	US2DF				
	US2GF US2JF				
					US2KF
	US2MF				
	Note	SPQ: 3,000pcs/Reel			
AiT provides all RoHS Compliant Products					

MECHANICAL DATA

Case: SMAF

Terminals: Solderable per MIL-STD-750,

Method 2026

Approx. Weight: 27mg 0.00086oz

PIN DESCRIPTION



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MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25 ambient temperature unless otherwise specified. Single phase half-wave 60 Hz, resistive or inductive load, for capacitive load current derate by 20 %.

Parameter		Symbol	US2AF	US2BF	US2DF	US2GF	US2JF	US2KF	US2MF	Unit
Maximum Repetitive Peak		V _{RRM}	50	100	200	400	600	800	1000	V
Reverse Voltage	Reverse Voltage		30	100	200	400	000	800	1000	V
Maximum RMS Volta	ge	V_{RMS}	35	70	140	280	420	560	700	V
Maximum DC Blockir	Maximum DC Blocking Voltage			100	200	400	600	800	1000	V
Maximum Average Forward			2.0							А
Rectified Current at T _A =65°C		I _{F(AV)}								
Peak Forward Surge	ak Forward Surge Current									
8.3ms Single Half Sine Wave		I _{FSM}								
Superimposed on Rated Load			50							Α
(JEDEC Method)										
Maximum Instantaneous		VF		4.0	1.4	4.7			\ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \	
Forward Voltage at 2A				1.0		1.4	1.7			V
Maximum DC										
Reverse Current at	T _A =25°C		5.0 100							μА
Rated DC	T _A =125°C	I _R								
Blocking Voltage										
Maximum Reverse R	Maximum Reverse Recovery									
Time ^{NOTE1}		trr	50				75			ns
Typical Thermal Resistance		R ₀ JA	50					°C/W		
Operating and Storage										00
Temperature Range		T _J , T _{STG} -55 ~150							°C	

NOTE1: Measured with I_{F} = 0.5 A, I_{R} = 1 A, I_{rr} = 0.25 A

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TYPICAL CHARACTERISTICS

Figure. 1 Forward Current Derating Curve

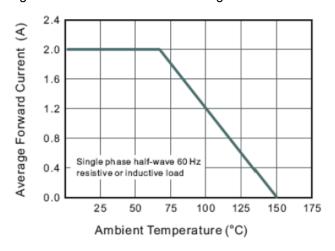


Figure. 3 Typical Instantaneous Forward Characteristics

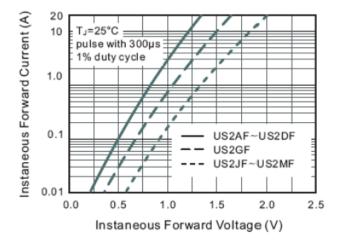


Figure. 2 Typical Reverse Characteristics

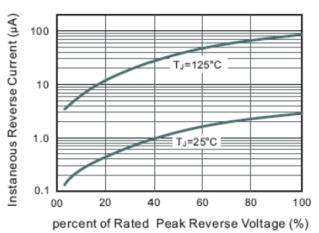
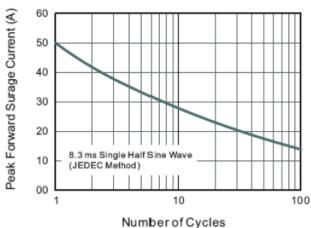


Figure. 4 Maximum Non-Repetitive Peak
Forward Surge Current

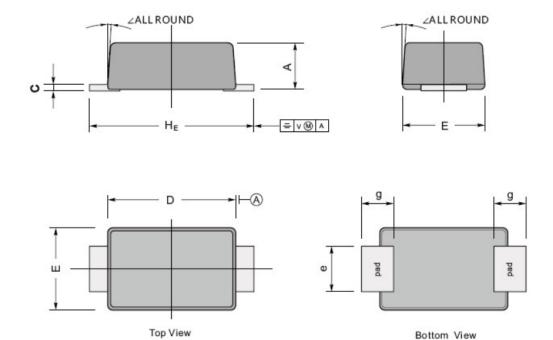


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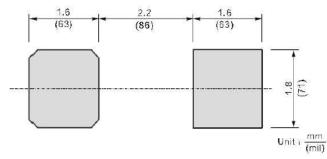
PACKAGE INFORMATION

Dimension in SMAF (Unit: mm)

Plastic surface mounted package; 2 leads



The recommended mounting pad size



UN	VIT	Α	С	D	Е	е	g	HE	4	
20.00	Max	1.1	0.20	3.7	2.7	1.6	1.2	4.9		
mm	Min	0.9	0.12	3.3	2.4	1.3	0.8	4.4	7°	
mil	Max	43	7.9	146	106	63	47	193	, , <u>, , , , , , , , , , , , , , , , , </u>	
	Min	35	4.7	130	94	51	31	173		

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